

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







SI-3000KF Series Low Current Consumption, Low Dropout Voltage

■Features

- · Compact full-mold package (equivalent to TO220)
- Output current: 1.0A
- Low dropout voltage: VDIF ≤ 0.5V (at Io = 1.0A)
- · High ripple rejection: 75dB
- Low circuit current at output OFF: Iq (OFF) ≤
- Built-in overcurrent and thermal protection circuits

■Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	Ratings SI-3010KF	Unit	Remarks
DC Input Voltage	Vin	35* ¹	V	
Output Control Terminal Voltage	Vc	Vin	V	
DC Output Current	lo	1.0	Α	
Power Dissipation	P _{D1}	16.6	W	With infinite heatsink
	PD2	1.72	W	Without heatsink, stand-alone operation
Junction Temperature	Tj	-40 to +125	°C	
Storage Temperature	Tstg	-40 to +125	°C	
Operating Ambient Temperature	Тор	-40 to +100	°C	
Thermal Resistance (Junction to Case)	θj-c	6.0	°C/W	
Thermal Resistance (Junction to Ambient Air)	θ j-a	58	°C/W	Without heatsink, stand-alone operation

^{*1:} A built-in input-overvoltage-protection circuit shuts down the output voltage at the Input Overvoltage Shutdown Voltage of the electrical characteristics.

■Applications

· Secondary stabilized power supply (local power supply)

■Recommended Operating Conditions

Parameter	Symbol	Ratings	
		SI-3010KF	Unit
Input Voltage Range	Vin	2.4*2 to 27*1	V
Output Current Range	lo	0 to 1.0 ⁻¹	Α
Output Voltage Variable Range	VoADJ	1.1 to 16	V
Operating Ambient Temperature	Тор	-30 to +85	°C
Operating Junction Temperature	Tj	-20 to +100	°C

^{*1:} VIN (max) and Io (max) are restricted by the relationship PD (max) = (VIN - VO) × IO = 16.6W.

■Electrical Characteristics

Parameter		Ratings						
	Symbol	SI-3010KF			Unit			
		min.	typ.	max.				
		VADJ	0.98	1.00	1.02			
Reference Voltage		Conditions	Vin=7V, lo=0.01A,			V		
				Vc=2V, Vo=5A				
		ΔVOLINE			30			
Line Regulation		Conditions		Vin=6 to 15V, Io=0.01A,				
		Conditions	Vc=2V, Vo=5A					
		ΔVOLOAD			75			
Load Re	egulation	Conditions		$V_{IN=7V}$, $I_{O=0}$ to 1A, $V_{C=2V}$,		mV		
		Conditions						
		VDIF			0.3			
		Conditions		Io=0.5A, Vc=2V, Vo=5V		V		
Dropout	Voltage				0.5	v		
		Conditions		Io=1.0A, Vc=2V, Vo=5V				
		Iq			600			
Juiesce	nt Circuit Current	Conditions		Vin=7V, Io=0A, Vc=2V		μΑ		
		Iq (OFF)			1	μА		
Circuit C	Current at Output OFF	Conditions	Vin=7V, Vc=0V					
		ΔVο/ΔΤα		±0.5				
Temperature Coefficient of Output Voltage		0	V _{IN=} 7V, lo=0.01A, Vc=2V, Tj=0 to 100°C, Vo=2.5V					
		Conditions						
Ripple Rejection		Rrej		75				
		0	V _{IN=7} V, Io=0.1A, Vc=2V, f=100 to 120Hz, Vo=5V			dB		
		Conditions						
Overcurrent Protection Starting Current*3		ls ₁	1.1					
		Conditions		Vin=7V, Vc=2V		A		
Control Voltage (Output		Vc, IH	2			.,		
	Control Voltage (Output ON)*4	Conditions		V _{IN} =7V		v		
	Control Voltage (Output OFF)	Vc, IL			0.8	V		
Terminal		Conditions		V _{IN=7} V				
	Control Current (Output ON)	Ic, IH			40			
		Conditions		VIN=7V, Vc=2V		μΑ		
	Control Current (Output OFF)	Ic, IL	-5	0		<u> </u>		
		Conditions	<u> </u>	V _{IN=7} V, V _{C=0} V		μΑ		
Input Overvoltage Shutdown Voltage		Vove	33	, 10 01				
		Conditions		Io=0.01A		v		

^{*3:} Is1 is specified at the 5% drop point of output voltage Vo on the condition that VIN = overcurrent protection starting current, Io = 10 mA.

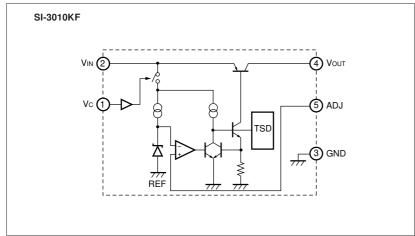
^{*2:} Refer to the Dropout Voltage parameter.

^{*4:} Output is OFF when the output control terminal Vc is open. Each input level is equivalent to LS-TTL level. Therefore, the device can be driven directly by LS-TTLs.

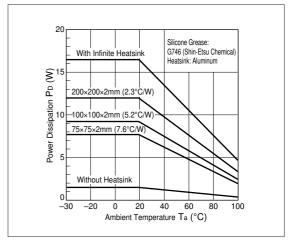
^{*5:} SI-3000KFE cannot be used in the following applications because the built-in foldback-type overcurrent protection may cause errors during start-up stage.

⁽¹⁾ Constant current load (2) Positive and negative power supply (3) Series-connected power supply (4) Vo adjustment by raising ground voltage

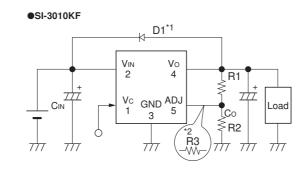
■Block Diagram



■Ta-PD Characteristics



■Typical Connection Diagram



C_{IN}: Input capacitor (22μ F or larger)

Co: Output capacitor (47 μ F or larger)

If a low ESR capacitor (such as a ceramic capacitor) is used for the output capacitor, oscillation may occur.

*1. D1: Reverse bias protection diode

This diode is required for protection against reverse biasing between the input and output. (Sanken RU2Z is recommended.)

R1, R2: Output voltage setting resistors

The output voltage can be adjusted by connecting R1 and R2 as shown above.

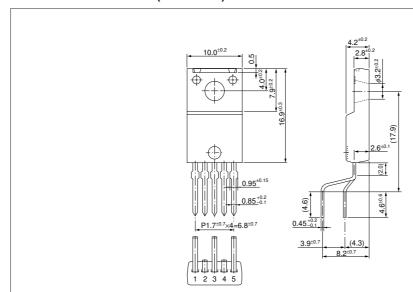
The recommended value for R2 is $10k\Omega$.

 $R1=(Vo-Vadj)\div(Vadj/R2)$

*2: Insert R3 in case of setting Vo to Vo \leq 1.5V. The recommended value for R3 is $10k\Omega$.

■External Dimensions (TO220F-5)

(Unit : mm)



Pin Assignment

- ① Vc
- ② VIN
- ③ GND
- 4 Vout5 ADJ

Plastic Mold Package Type Flammability: UL 94V-0 Product Mass: Approx. 2.3 g